

HAT2033R, HAT2033RJ

Silicon N Channel Power MOS FET High Speed Power Switching

REJ03G1165-0400

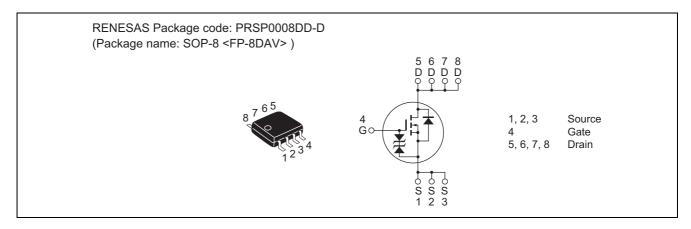
(Previous: ADE-208-664B)

Rev.4.00 Sep 07, 2005

Features

- For Automotive Application (at Type Code "J")
- Low on-resistance
- Capable of 4 V gate drive
- High density mounting

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item		Symbol	Value	Unit
Drain to source voltage		V _{DSS}	60	V
Gate to source voltage		V_{GSS}	±20	V
Drain current		I _D	7	Α
Drain peak current		I _{D (pulse)} Note 1	56	Α
Body-drain diode reverse drain current		I _{DR}	7	Α
Avalanche current	HAT2033R	I _{AP} Note 4	_	_
	HAT2033RJ		7	Α
Avalanche energy	HAT2033R	E _{AR} Note 4	_	_
	HAT2033RJ		4.2	mJ
Channel dissipation		Pch Note 2	2.5	W
Channel temperature		Tch	150	°C
Storage temperature		Tstg	−55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

- 2. When using the glass epoxy board (FR4 $40\times40\times1.6$ mm), PW ≤10 s
- 3. Value at Tch = 25°C, Rg \geq 50 Ω

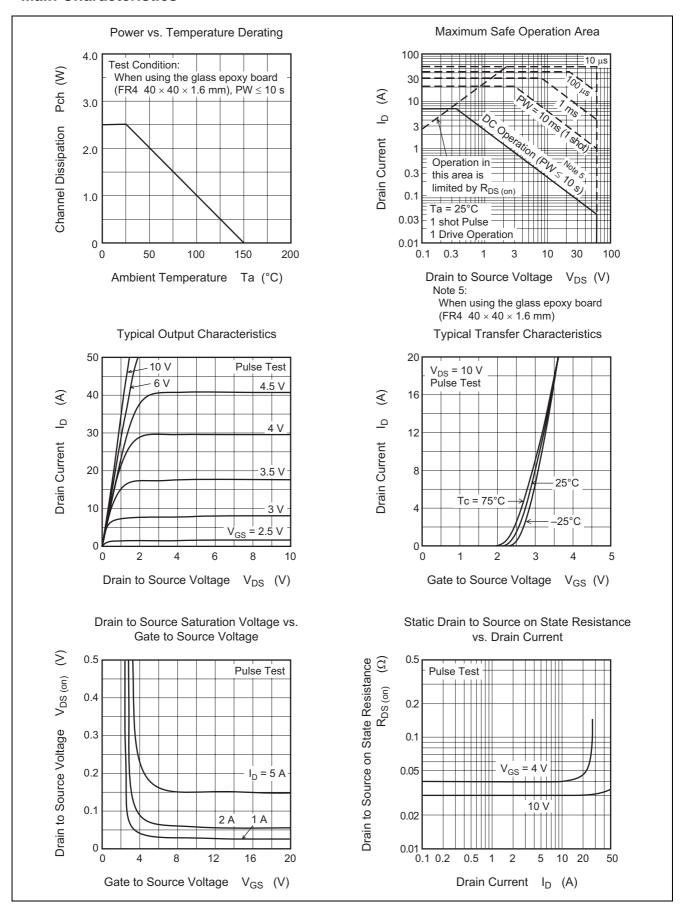
Electrical Characteristics

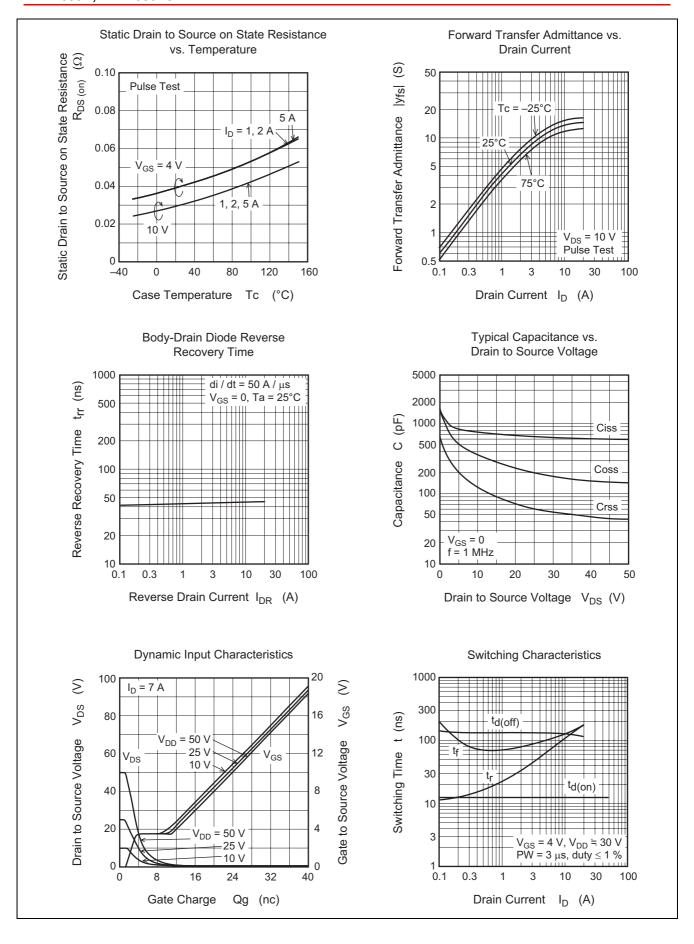
 $(Ta = 25^{\circ}C)$

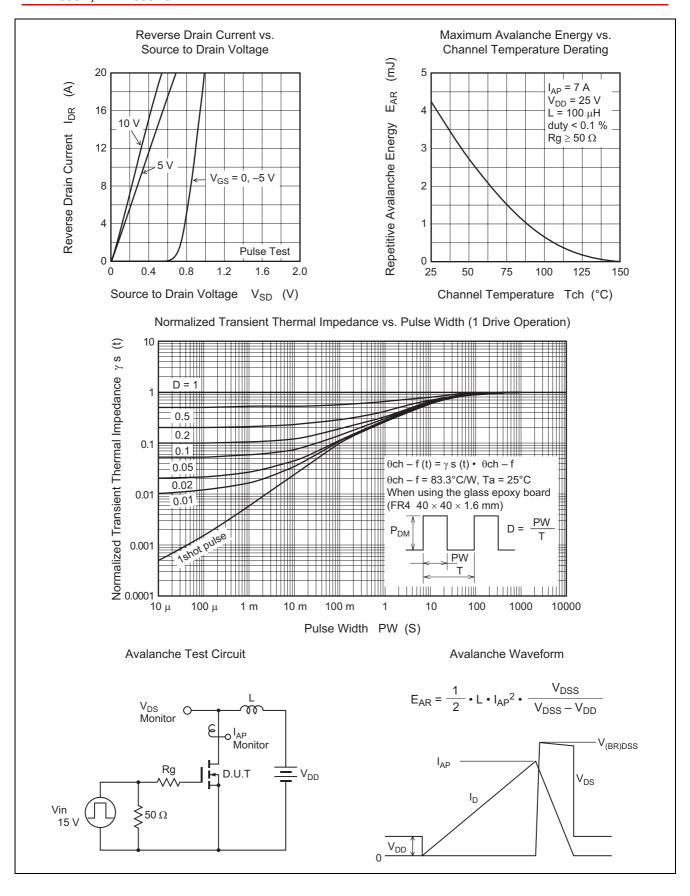
Item		Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage		V _{(BR) DSS}	60	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage		V _{(BR) GSS}	±20	_	_	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current		I _{GSS}	_	_	±10	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain	HAT2033R	I _{DSS}	_	_	1	μΑ	$V_{DS} = 60 \text{ V}, V_{GS} = 0$
current	HAT2033RJ	I _{DSS}	_	_	0.1	μΑ	
Zero gate voltage drain	HAT2033R	I _{DSS}	_	_	_	μΑ	$V_{DS} = 48 \text{ V}, V_{GS} = 0$
current	HAT2033RJ	I _{DSS}	_	_	10	μΑ	Ta = 125°C
Gate to source cutoff voltage		V _{GS (off)}	1.2	_	2.2	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Static drain to source on state resistance		R _{DS (on)}	_	0.03	0.038	Ω	$I_D = 4 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note 4}}$
		R _{DS (on)}	_	0.04	0.053	Ω	$I_D = 4 \text{ A}, V_{GS} = 4 \text{ V}^{\text{Note 4}}$
Forward transfer admittance		y _{fs}	6.5	10	_	S	$I_D = 4 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note 4}}$
Input capacitance		Ciss		740	_	pF	V _{DS} = 10 V
Output capacitance		Coss		370	_	pF	$V_{GS} = 0$
Reverse transfer capacitance		Crss		130	_	pF	f = 1 MHz
Turn-on delay time		t _{d (on)}	_	13	_	ns	$V_{GS} = 10 \text{ V}, I_D = 4 \text{ A},$
Rise time		t _r	_	55	_	ns	$V_{DD} \cong 30 \text{ V}$
Turn-off delay time		t _{d (off)}	_	140	_	ns	
Fall time		t _f	_	95	_	ns	
Body-drain diode forward voltage		V_{DF}	_	0.82	1.07	V	$I_F = 7 \text{ A}, V_{GS} = 0^{\text{Note 4}}$
Body-drain diode reverse recovery time		t _{rr}	_	45	_	ns	I _F = 7 A, V _{GS} = 0
							di _F /dt = 50 A/μs

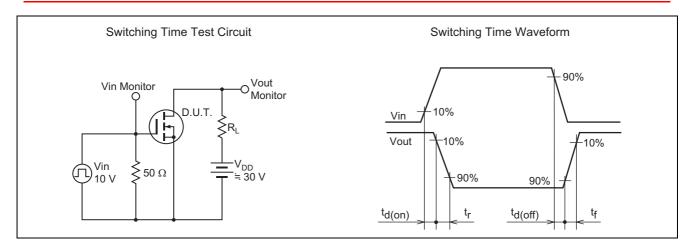
Note: 4. Pulse test

Main Characteristics

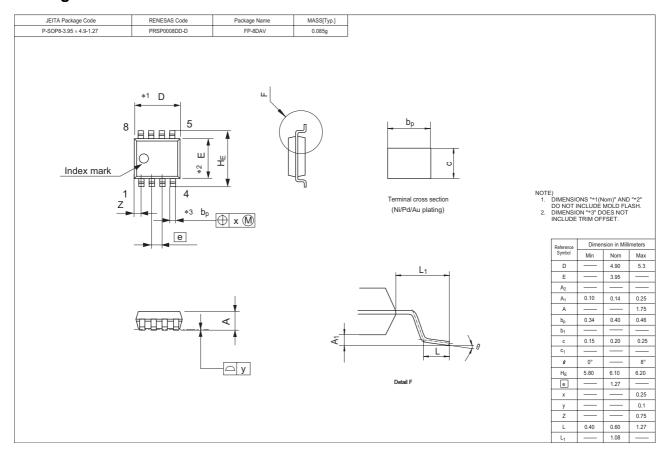








Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
HAT2033R-EL-E	2500 pcs	Taping
HAT2033RJ-EL-E	2500 pcs	Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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